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74LCX00 Low Voltage Quad 2-Input NAND Gate with 5V Tolerant Inputs

Features

- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 5.2ns t_{PD} max. (V_{CC} = 3.3V), 10µA I_{CC} max.
- Power down high impedance inputs and outputs
- ±24mA output drive (V_{CC} = 3.0V)
- Implements proprietary noise/EMI reduction circuitry
- Latch-up performance exceeds JEDEC 78 conditions
- ESD performance:
- Human body model > 2000V
- Machine model > 200V
- Leadless DQFN package

Ordering Information

General Description

The LCX00 contains four 2-input NAND gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The 74LCX00 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

	mation					
Order Number	Package Number	Package Description				
74LCX00M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow				
74LCX00SJ	M14D	4-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide				
74LCX00BQX ⁽¹⁾	MLP14A	14-Terminal Depopulated Quad Very-Thin Flat Pack No Leads (DQFN), JEDEC MO-241, 2.5 x 3.0mm				
74LCX00MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide				

Note:

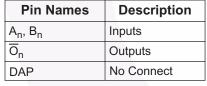
1. DQFN package available in Tape and Reel only.

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

All packages are lead free per JEDEC: J-STD-020B standard.

74LCX00 — Low Voltage Quad 2-Input NAND Gate with 5V Tolerant Inputs

Connection Diagrams Pin Assignments for SOIC, SOP, and TSSOP Ao Vcc 13 B_0 Α2 12 \overline{O}_0 ō, A_1 10 B₁ 9 ō, Đ, 8 GND ō, Pad Assignments for DQFN VCC 14 1 13 B₀ 2 (13 A2 ō 3 (12 B2 D A1 (11 O2 4 A B₁ 5 (10 A3 P 01 6 (9 B3 9



GND 03

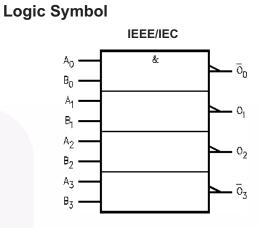
(Top View)

8 7

(Bottom View)

Note: DAP (Die Attach Pad)

Pin Description



Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5V to +7.0V
VI	DC Input Voltage	-0.5V to +7.0V
Vo	DC Output Voltage, Output in HIGH or LOW State ⁽²⁾	-0.5V to V _{CC} + 0.5V
I _{IK}	DC Input Diode Current, V _I < GND	–50mA
I _{ОК}	DC Output Diode Current	
	V _O < GND	–50mA
	V _O > V _{CC}	+50mA
Ι _Ο	DC Output Source/Sink Current	±50mA
I _{CC}	DC Supply Current per Supply Pin	±100mA
I _{GND}	DC Ground Current per Ground Pin	±100mA
T _{STG}	Storage Temperature	–65°C to +150°C

Note:

2. I_O Absolute Maximum Rating must be observed.

Recommended Operating Conditions⁽³⁾

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Units
V _{CC}	Supply Voltage			
	Operating	2.0	3.6	V
	Data Retention	1.5	3.6	
VI	Input Voltage	0	5.5	V
Vo	Output Voltage, HIGH or LOW State	0	V _{CC}	V
I _{OH} / I _{OL}	Output Current			
	$V_{CC} = 3.0V - 3.6V$		±24	mA
	$V_{CC} = 2.7V - 3.0V$		±12	
	$V_{CC} = 2.3V - 2.7V$		±8	
T _A	Free-Air Operating Temperature	-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, $V_{IN} = 0.8V-2.0V$, $V_{CC} = 3.0V$	0	10	ns/V

Note:

3. Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

	Parameter			T _A = -40°C to +85°C		
Symbol		V _{CC} (V)	Conditions	Min.	Max.	Units
V _{IH}	HIGH Level Input Voltage	2.3–2.7		1.7		V
		2.7–3.6		2.0		
V _{IL}	LOW Level Input Voltage	2.3–2.7			0.7	V
		2.7–3.6			0.8	
V _{OH}	HIGH Level Output Voltage	2.3–3.6	I _{OH} = -100μA	V _{CC} - 0.2		V
		2.3	$I_{OH} = -8mA$	1.8		
		2.7	$I_{OH} = -12mA$	2.2		
		3.0	$I_{OH} = -18 \text{mA}$	2.4		
			$I_{OH} = -24 \text{mA}$	2.2		
V _{OL}	LOW Level Output Voltage	2.3–3.6	$I_{OL} = 100 \mu A$		0.2	V
		2.3	$I_{OL} = 8 mA$		0.6	
		2.7	I _{OL} = 12mA		0.4	
		3.0	$I_{OL} = 16 \text{mA}$		0.4	1
			$I_{OL} = 24mA$		0.55	
l _l	Input Leakage Current	2.3–3.6	$0 \le V_I \le 5.5V$		±5.0	μA
I _{OFF}	Power-Off Leakage Current	0	$V_{\rm I}$ or $V_{\rm O} = 5.5 V$		10	μA
I _{CC}	Quiescent Supply Current	2.3–3.6	$V_{I} = V_{CC}$ or GND		10	μA
			$3.6V \le V_I \le 5.5V$		±10	
ΔI_{CC}	Increase in I _{CC} per Input	2.3–3.6	$V_{IH} = V_{CC} - 0.6V$		500	μA

AC Electrical Characteristics

		$T_A = -40^{\circ}$ C to +85°C, $R_L = 500\Omega$						
		$V_{CC} = 3.3V \pm 0.3V,$ $C_{L} = 50 \text{pF}$		V _{CC} = 2.7V, C _L = 50pF		$V_{CC} = 2.5V \pm 0.2V,$ $C_L = 30 \text{pF}$		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PHL} , t _{PLH}	Propagation Delay	1.5	5.2	1.5	6.0	1.5	6.2	ns
t _{OSHL} , t _{OSLH}	Output to Output Skew ⁽⁴⁾		1.0					ns

Note:

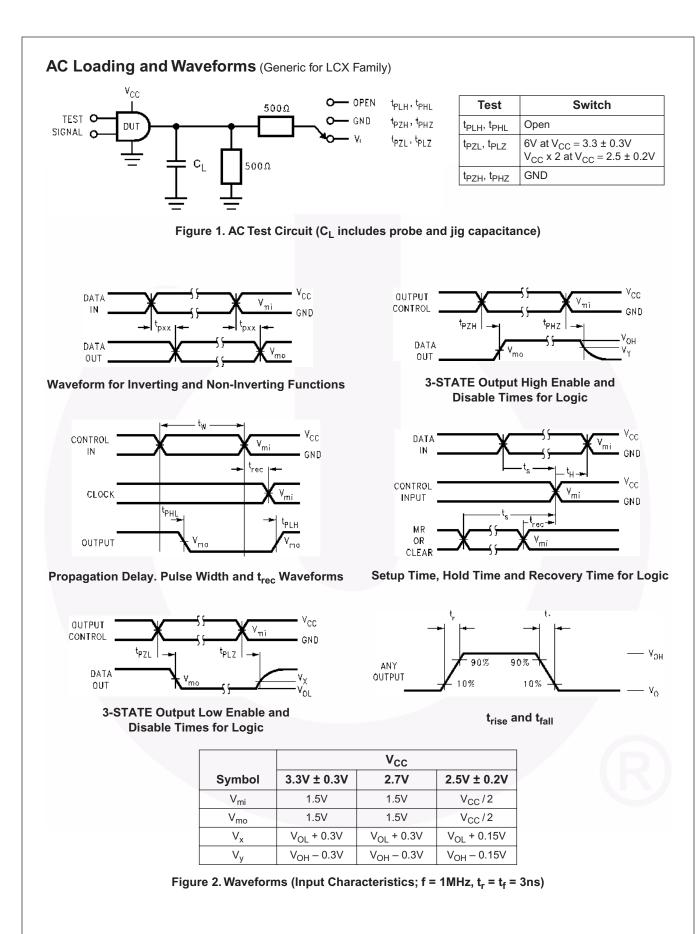
4. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

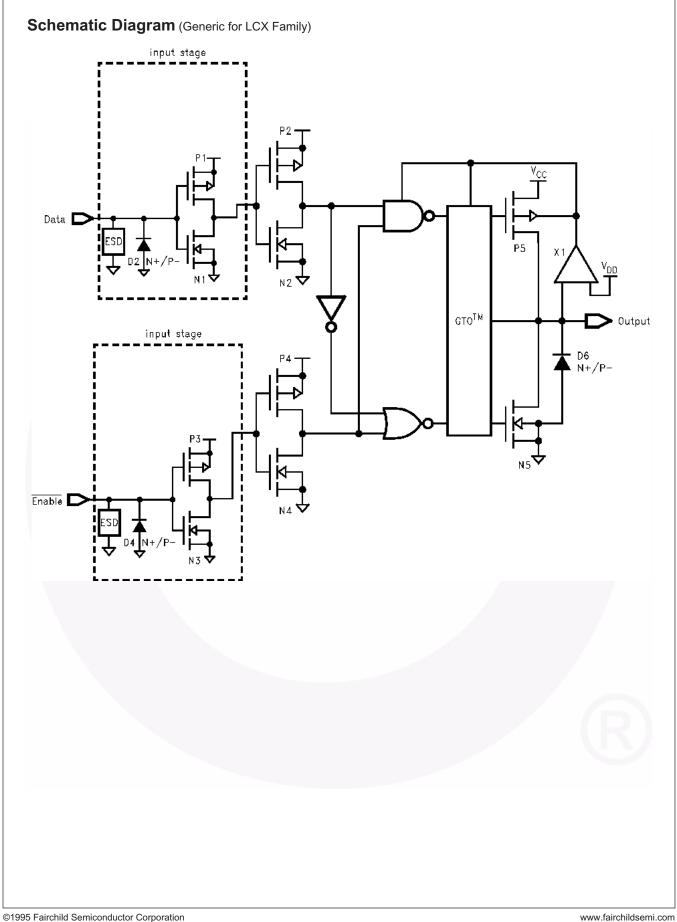
Dynamic Switching Characteristics

				$T_A = 25^{\circ}C$	
Symbol	Parameter	V _{CC} (V)	Conditions	Typical	Unit
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	3.3	$C_L = 50 pF, V_{IH} = 3.3V, V_{IL} = 0V$	0.8	V
		2.5	$C_L = 30 pF$, $V_{IH} = 2.5 V$, $V_{IL} = 0 V$	0.6	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	3.3	$C_L = 50 pF, V_{IH} = 3.3V, V_{IL} = 0V$	-0.8	V
		2.5	$C_{L} = 30 pF, V_{IH} = 2.5V, V_{IL} = 0V$	-0.6	

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3 V$, $V_I = 0 V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10MHz	25	pF





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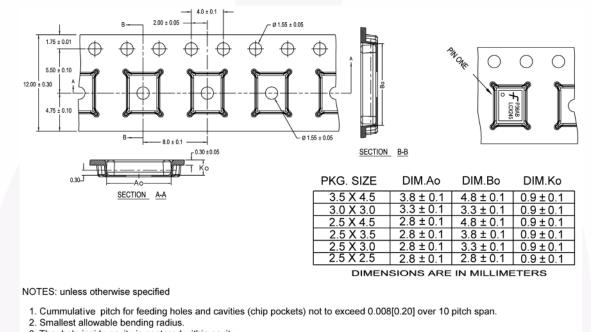
74LCX00 — Low Voltage Quad 2-Input NAND Gate with 5V Tolerant Inputs

Tape and Reel Specification

Tape Format for DQFN

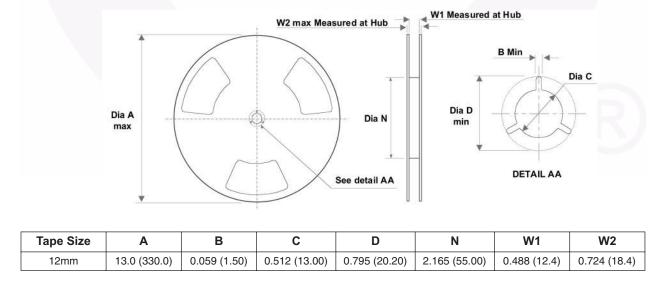
Package Designator	Tape Section	Number of Cavities	Cavity Status	Cover Tape Status	
BQX	BQX Leader (Start End)		Empty	Sealed	
	Carrier	3000	Filled	Sealed	
	Trailer (Hub End)	75 (Тур.)	Empty	Sealed	

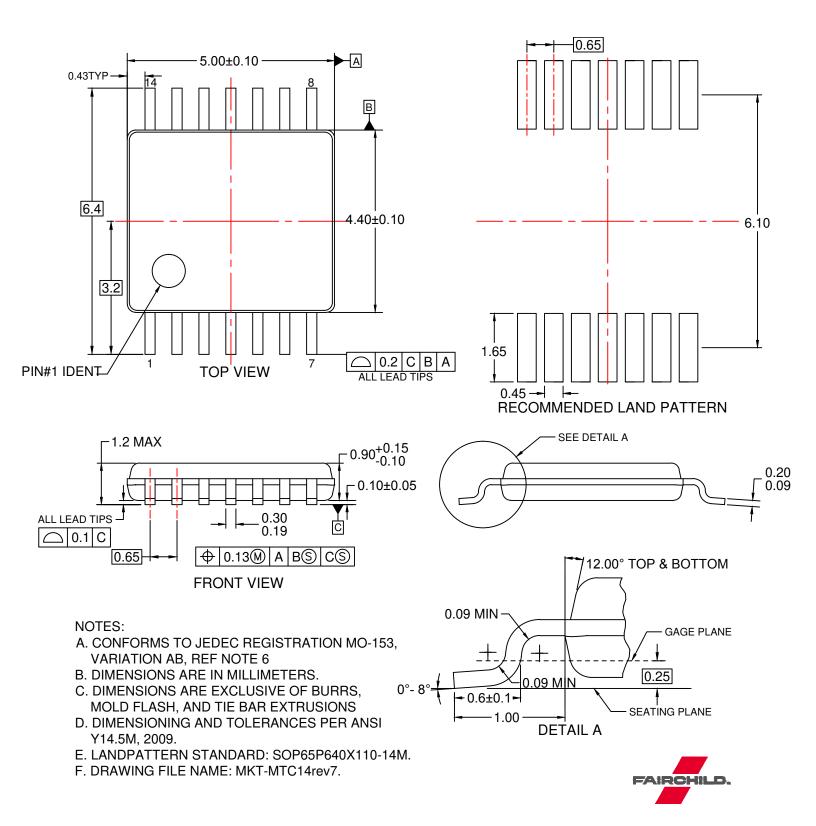
Tape Dimensions inches (millimeters)

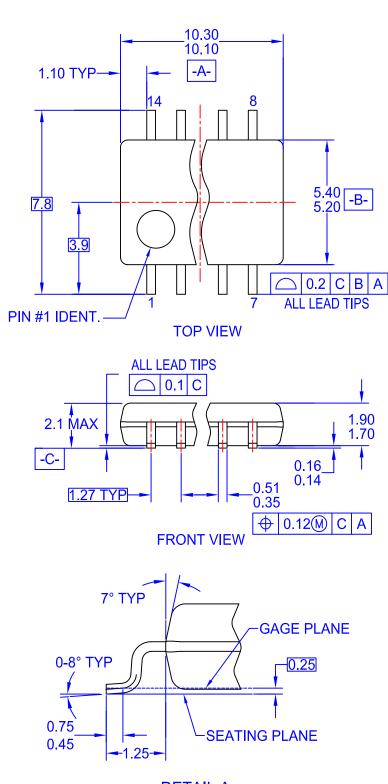


- 3. Thru hole inside cavity is centered within cavity.
- 4. Tolerance is ±0.002[0.05] for these dimensions on all 12mm tapes.
- 5. Ao and Bo measured on a plane 0.120[0.30] above the bottom of the pocket.
- 6. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
- 7. Pocket position relative to sprocket hole measured as true position of pocket. Not pocket hole.
- 8. Controlling dimension is millimeter. Diemension in inches rounded.

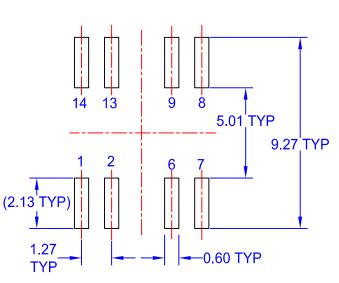
Reel Dimensions inches (millimeters)



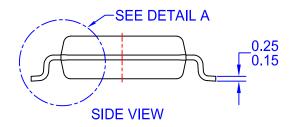








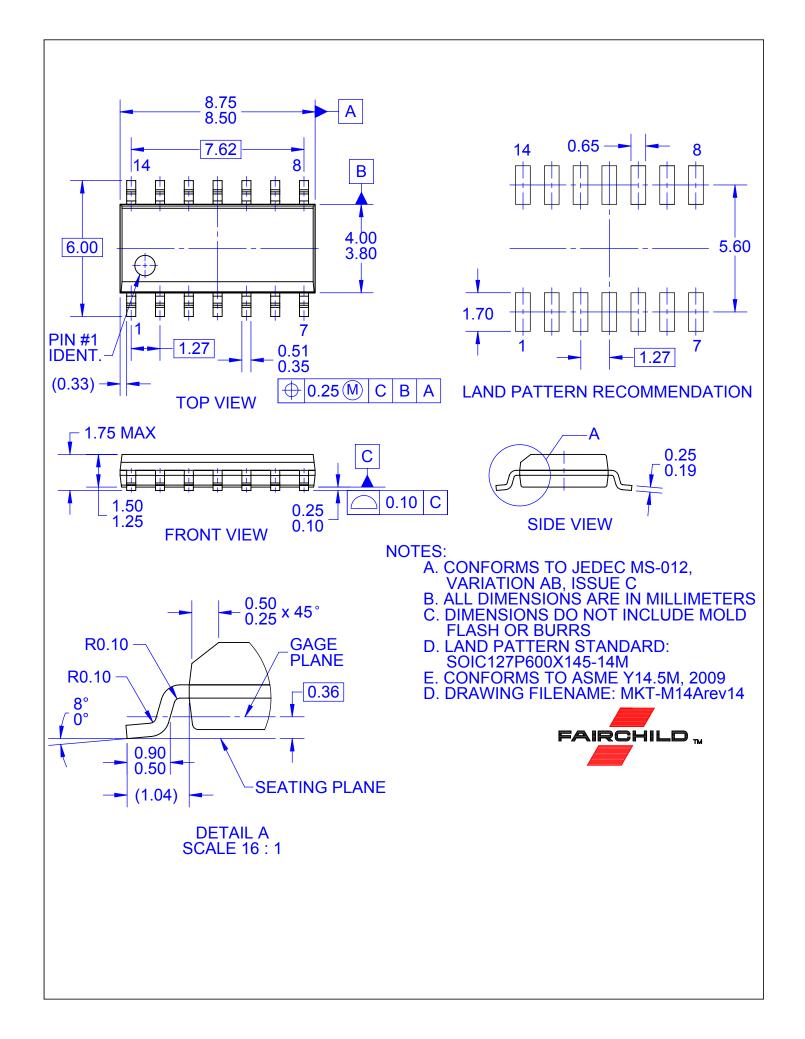
LAND PATTERN RECOMMENDATION

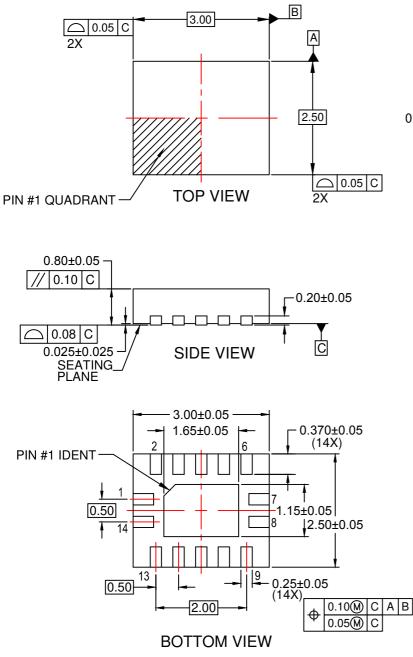


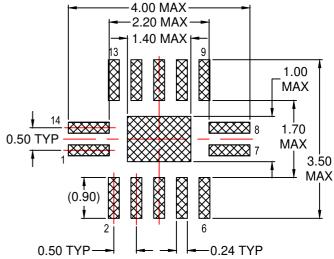
NOTES:

- A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.
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- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- D. DRAWING FILENAME: MKT-M14Drev4.









RECOMMENDED LAND PATTERN

NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MO-241, VARIATION AA
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- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN.
- E. DRAWING FILENAME: MKT-MLP14Arev2.



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